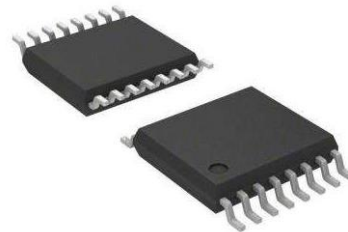


## Four Channel LVDS Differential Cable Driver

### PRODUCT DESCRIPTION

The MS21147T is a four channel LVDS differential cable driver, meeting the amplitude characteristic of multi-point low voltage differential signaling (MLVDS). Each current-mode driver provides 590mV differential output voltage for 100Ω external differential load.

The MS21147T is applied for point-to-point and multi-point base-band data transmission through 100Ω controlled impedance media. The transmission media could be PCB traces, backplane or cables. The ultimate data rate and distance depend on the media attenuation characteristic, the noise coupled with environment and other system characteristics.



TSSOP16

### FEATURES

- 200Mbps (100MHz) Data Rate
- Propagation Delay Time 3ns (Typical Value)
- Output High Impedance on Power-down Mode
- 3.3V Power Supply
- ±600mV Differential Signal
- Operating Temperature Range: -40°C to 125°C

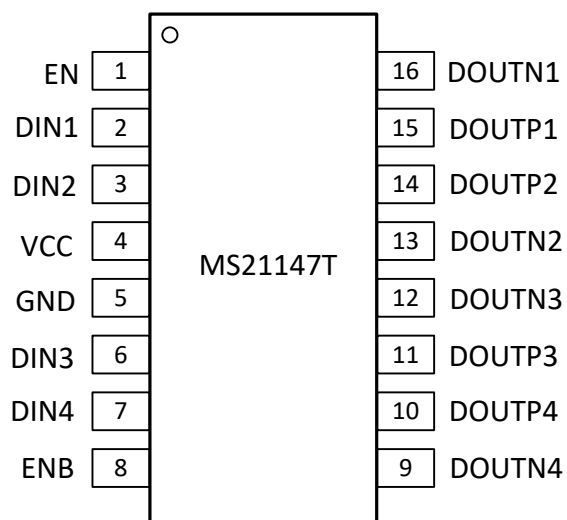
### APPLICATIONS

- Multi-function Printer
- Flat Panel Display Interface
- Monitoring Camera

### PRODUCT SPECIFICATION

Part Number	Package	Marking
MS21147T	TSSOP16	MS21147T

## PIN CONFIGURATION

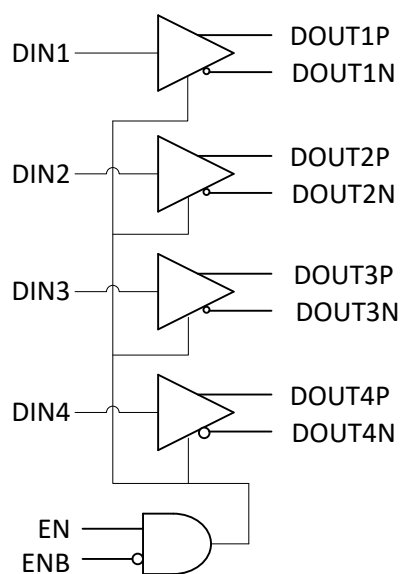


## PIN DESCRIPTION

Pin	Name	Type	Description
1	EN	I	Enable Input
2	DIN1	I	Data Input (Channel 1), TTL or CMOS Logical Level
3	DIN2	I	Data Input (Channel 2), TTL or CMOS Logical Level
4	VCC	-	Power Supply
5	GND	-	Ground
6	DIN3	I	Data Input (Channel 3), TTL or CMOS Logical Level
7	DIN4	I	Data Input (Channel 4), TTL or CMOS Logical Level
8	ENB	I	Enable Input
9	DOUTN4	O	Negative Output (Channel 4), MLVDS Level
10	DOUTP4	O	Positive Output (Channel 4), MLVDS Level
11	DOUTP3	O	Positive Output (Channel 3), MLVDS Level
12	DOUTN3	O	Negative Output (Channel 3), MLVDS Level
13	DOUTN2	O	Negative Output (Channel 2), MLVDS Level
14	DOUTP2	O	Positive Output (Channel 2), MLVDS Level
15	DOUTP1	O	Positive Output (Channel 1), MLVDS Level
16	DOUTN1	O	Negative Output (Channel 1), MLVDS Level

Note: Not used data input pins are left floating.

## BLOCK DIAGRAM



## ABSOLUTE MAXIMUM RATINGS

Any exceeding absolute maximum rating application causes permanent damage to device. Because long-time absolute operation state affects device reliability. Absolute ratings just conclude from a series of extreme tests. It doesn't represent chip can operate normally in these extreme conditions.

Parameter	Symbol	Ratings	Unit
Power Supply Voltage	$V_{CC}$	-0.5 ~ +4	V
Inputs and Outputs Voltage	$V_{CCIO}$	-0.5 ~ ( $V_{CC}+0.3$ )	V
ESD (HBM)	$V_{ESD}$	>10	kV
Operating Temperature Range	$T_A$	-40 ~ +125	°C
Storage Temperature Range	$T_{STG}$	-65 ~ +150	°C
Soldering Temperature(10s)	$T_{SOLDER}$	260	°C

## RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Min	Typ	Max	Unit
Power Supply Voltage	$V_{CC}$	3	3.3	3.6	V
Input Voltage Range	$V_{IN}$	GND		$V_{CC}$	V
Signal Rate	$1/t_{UI}$			200	Mbps
Operating Temperature Range	$T_A$	-40		125	°C

## ELECTRICAL CHARACTERISTICS

Typical values are  $V_{CC} = 3.3V$ , external differential  $R_L = 100\Omega$ ,  $C_L = 15pF$ ,  $T_A = +25^\circ C$ . Unless otherwise noted.

### Electrical Characteristics

Parameter	Symbol	Pin	Condition	Min	Typ	Max	Unit
Differential Output Voltage	$V_{OD}$	DOUTP, DOUTN	$R_L = 100\Omega$ (Figure 1)	590	600	620	mV
Differential Output Voltage Difference(Complementary )	$\Delta V_{OD}$			1	10	20	mV
Common-mode Output Voltage	$V_{OS}$			1.1	1.144	1.16	V
Common-mode Output Voltage Difference(Complementary )	$\Delta V_{OS}$				0	10	mV
Output High Level	$V_{OH}$	DIN, EN, ENB	$R_L = 100\Omega$	1.42	1.442	1.461	V
Output Low Level	$V_{OL}$			0.823	0.846	0.858	V
Input High Level	$V_{IH}$			2.0		$V_{CC}$	V
Input Low Level	$V_{IL}$			GND		0.8	V
Input Current	$I_I$	DOUTP, DOUTN	Input= $V_{CC}$ , GND, 2.5V or 0.4V	-10	$\pm 1$	+10	$\mu A$
Input Clamping Voltage	$V_{CL}$		$I_{CL} = -18mA$	-1.1	-0.77		V
Output Short-circuit Current	$I_{OS}$	DOUTP, DOUTN	DOUTP or DOUTN=0V	-8.0	-7.8		mA
Output Three-state Current	$I_{OZ}$		$V_{CC} = 3.3V$ , EN=0.8V, ENB=2.0V $ DOUTP-DOUTN  = 3.6V$		$\pm 80$		$\mu A$
Power-down Current	$I_{OFF}$	DOUTP, DOUTN	$V_{CC}$ Power down, $ DOUTP-DOUTN  = 3.6V$		7.4		mA
			$V_{CC}$ Power down, MS21148T as receiver		4.4 <sup>1</sup>		$\mu A$
No-load Power Supply Current, Driver Enabled	$I_{CC}$	VCC	DIN= $V_{CC}$ or GND		8.0	8.2	mA
With-load Power Supply Current, Driver Enabled	$I_{CCL}$	VCC	$R_L = 100\Omega$ DIN= $V_{CC}$ or GND		31	32	mA
No-load Power Supply Current, Driver Disabled	$I_{CCZ}$	VCC	DIN= $V_{CC}$ or GND EN=GND, ENB= $V_{CC}$		3.1	4.0	mA

Note 1: The test corresponds to the situation where the MS21148T is in work while the MS21147T is in power-down state. If the MS21147T and the MS21148T all work or power down at the same time, DOUTP/DOUTN input currents approach 0.

## Switching Characteristics

$V_{CC} = 3.3V$ ,  $T_A = +25^{\circ}C$  <sup>2</sup>.

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Differential Propagation Delay (High to Low)	$t_{PHLD}$	$R_L=100\Omega$ , $C_L=15pF$ <sup>3</sup> Figure 2 and Figure 3	2.5	3.0	4.0	ns
Differential Propagation Delay (Low to High)	$t_{PLHD}$		2.5	3.0	4.0	ns
Differential Propagation Delay Skew $ t_{PHLD} - t_{PLHD} $	$t_{SDK}$		0	100	300	ps
Channel Propagation Delay Skew <sup>4</sup>	$t_{SK1}$		0	100	300	ps
Rise Time	$t_R$			2		ns
Fall Time	$t_F$			1.8		ns
Output High Level to High Impedance Delay	$t_{PHZ}$	$R_L=100\Omega$ , $C_L=15pF$ <sup>3</sup> Figure 4 and Figure 5		4		ns
Output Low Level to High Impedance Delay	$t_{PLZ}$			4		ns
Output High Impedance to High Level Delay	$t_{PZH}$			8.4		ns
Output High Impedance to Low Level Delay	$t_{PZL}$			5.7		ns
Maximum Operating Frequency	$f_{MAX}$			100		MHz

Note:

2. Normal test for input signal:  $f=1MHz$ ,  $Z_0=50\Omega$ .
3. Load capacitance includes probe and soldering capacitance.
4. Channel Propagation Delay Skew is the maximum propagation delay difference between four channels.

## Test Circuit

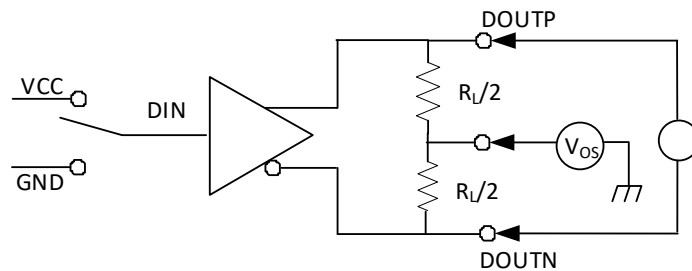


Figure 1.  $V_{OD}$ ,  $V_{OS}$  Test Circuit

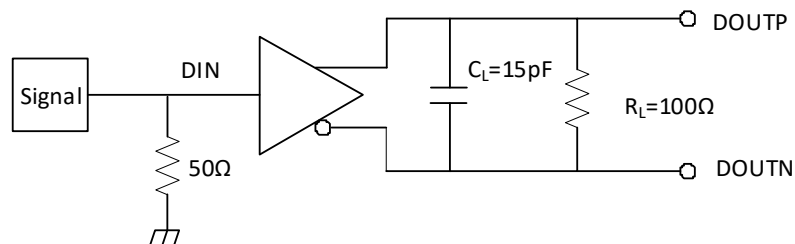


Figure 2. Propagation Delay and Edge Transition Time Test Circuit

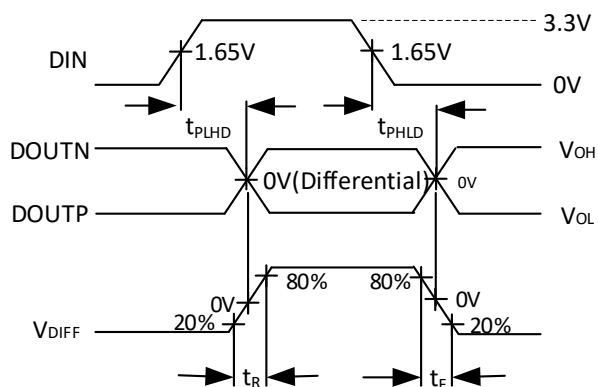


Figure 3. Propagation Delay and Edge Transition Time Waveform

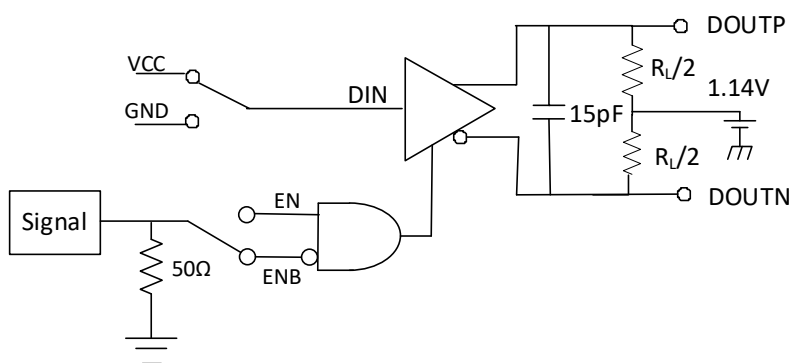


Figure 4. Three-state Delay Test Circuit

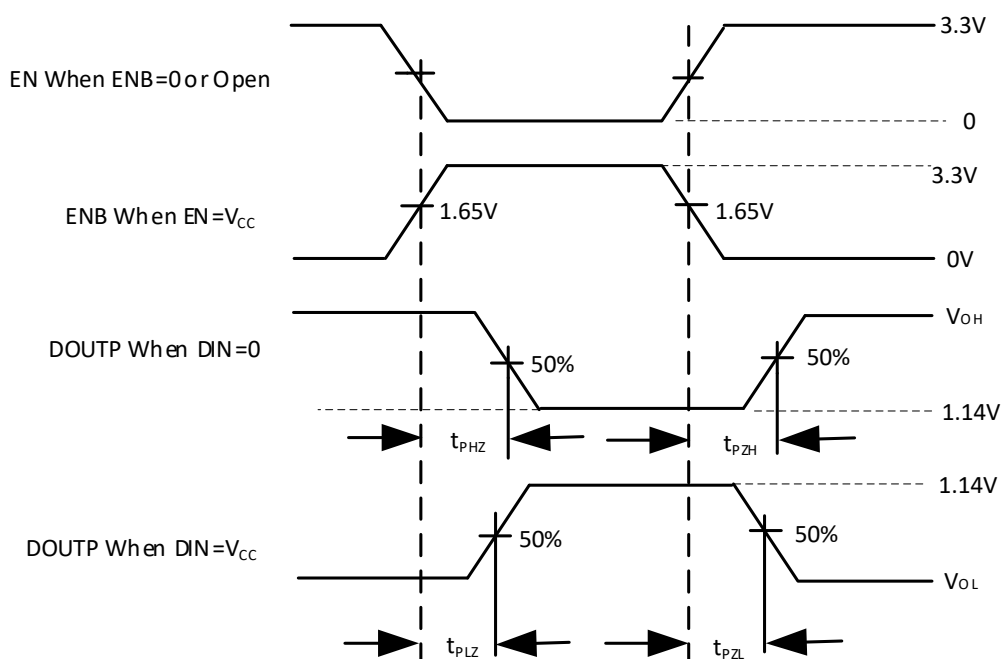
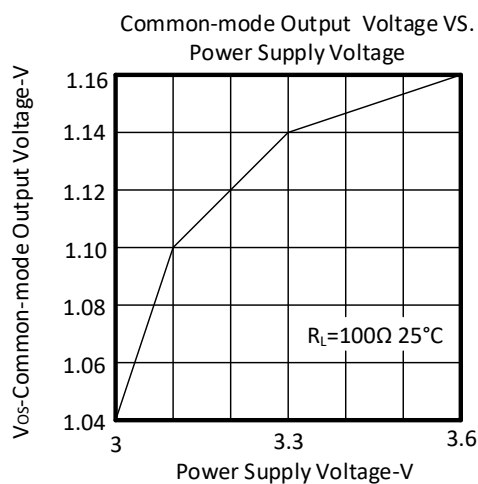
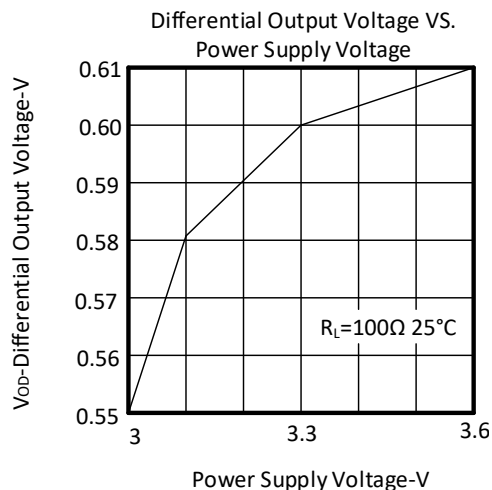
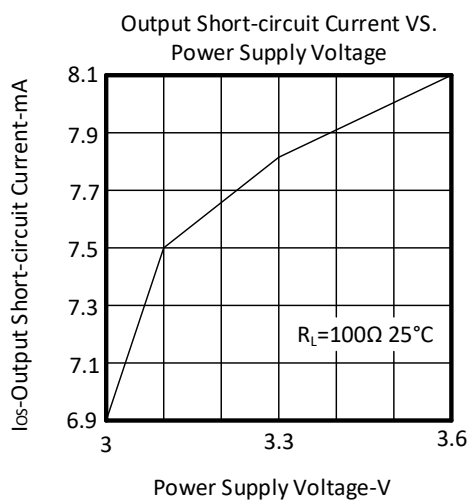
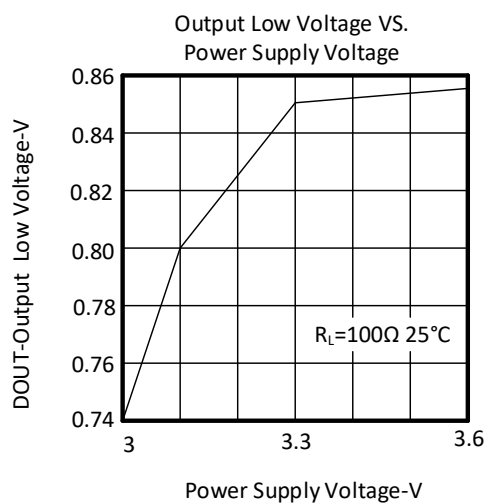
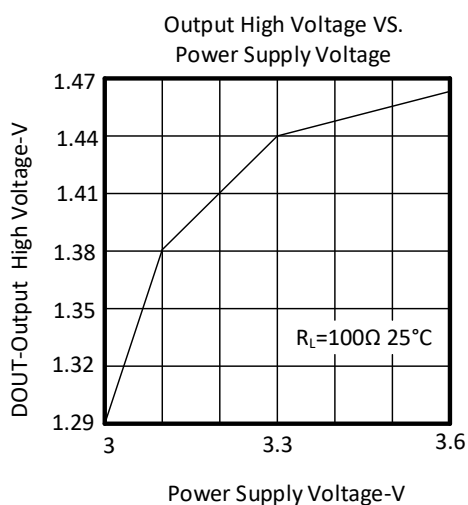
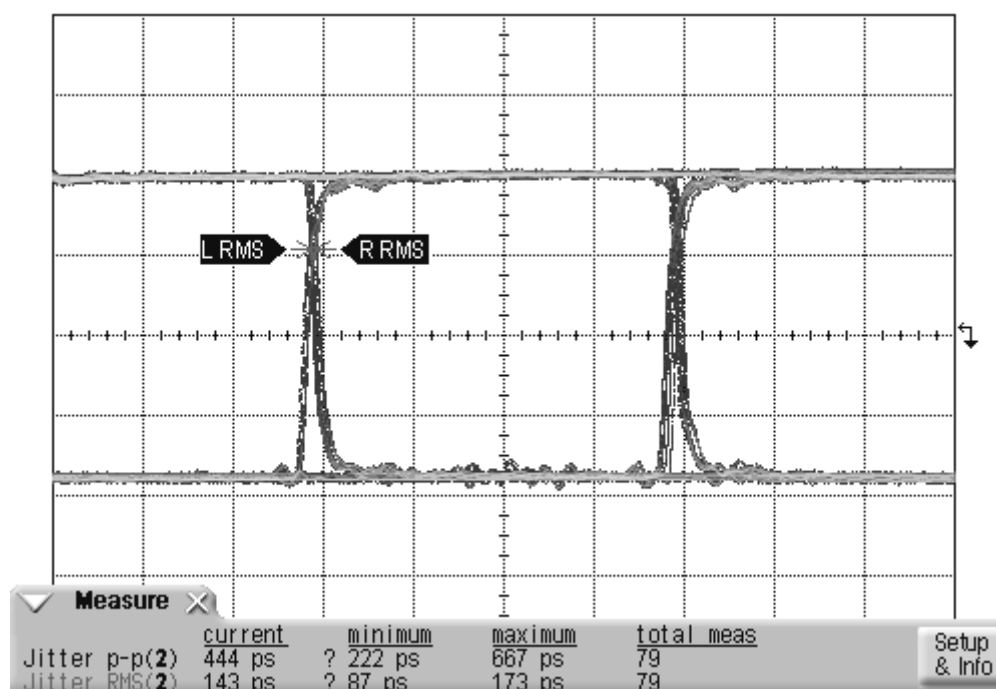


Figure 5. Three-state Delay Waveform

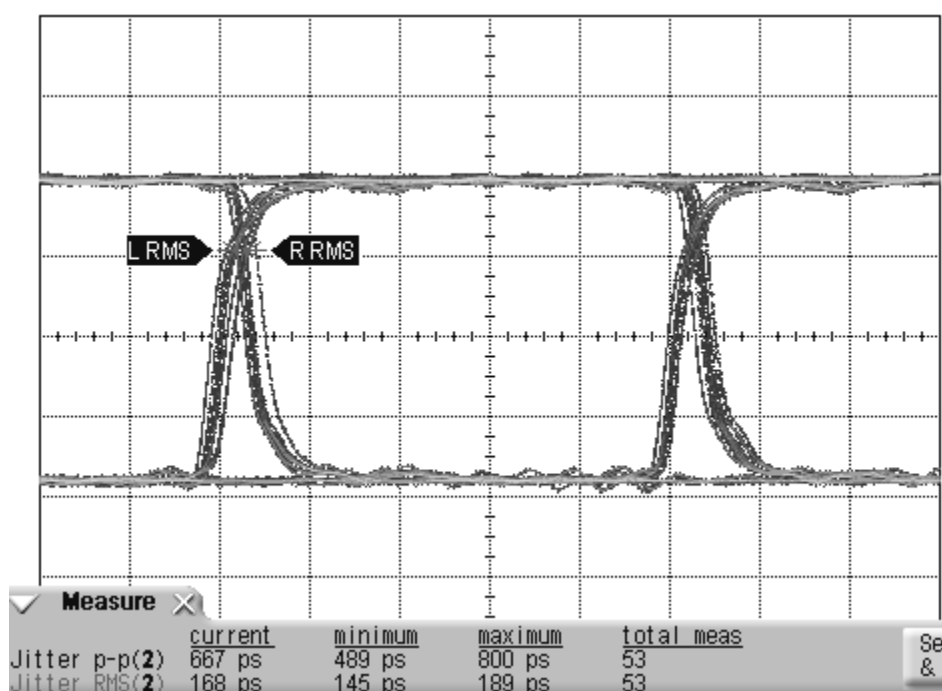
## TYPICAL OPERATING CURVE



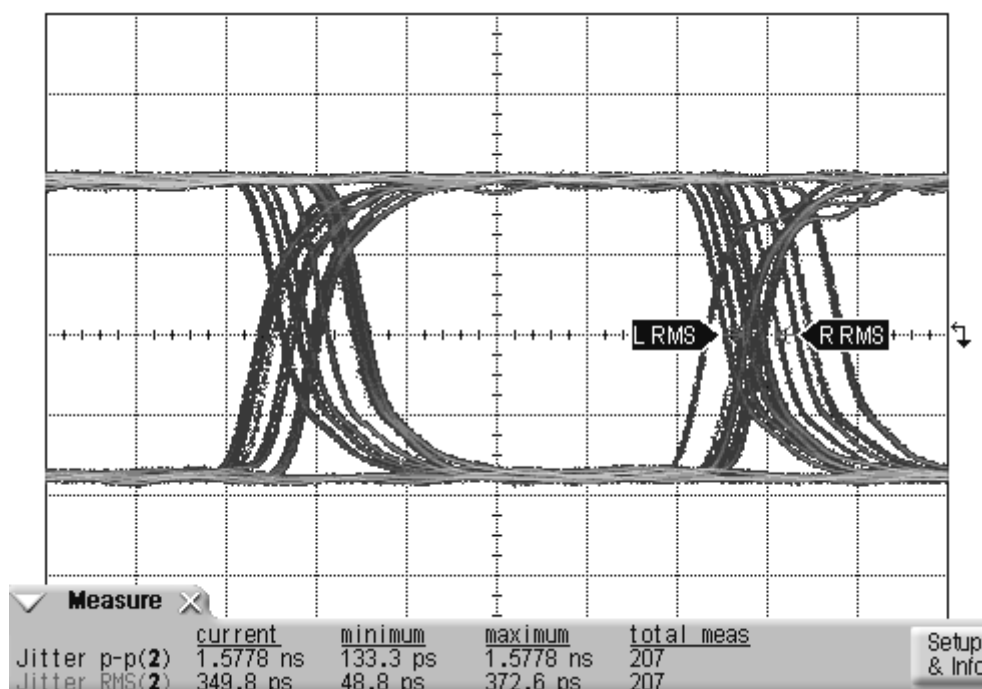




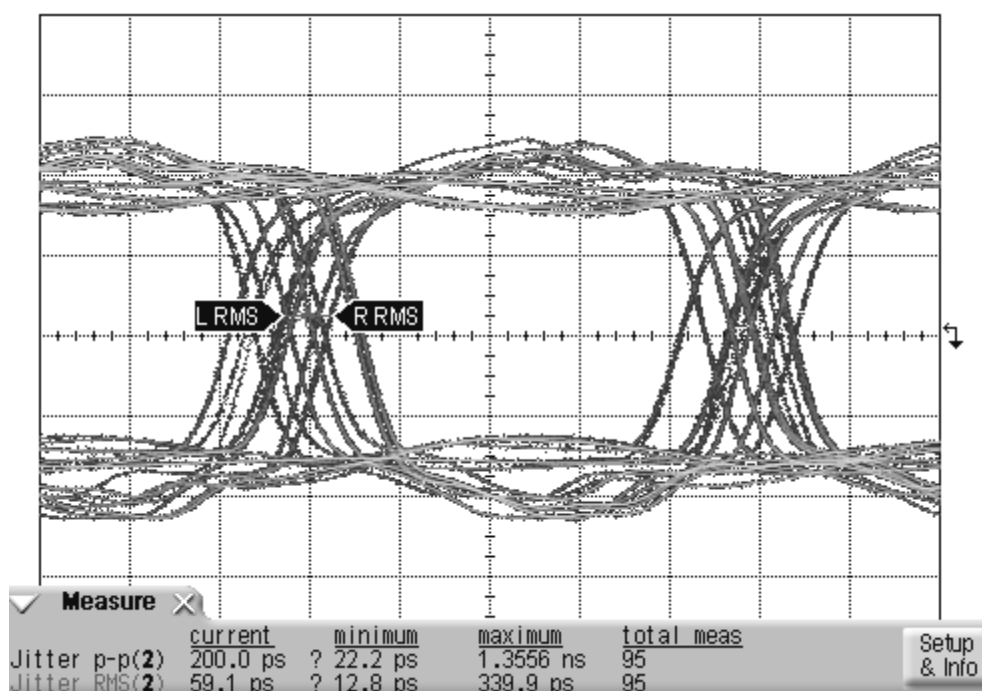
The Eye Diagram of the MS21147T as Driver and the MS21148T as Receiver:  $V_{CC}=3.3V$ , PRBS7 50Mbps CAT5E 10m



The Eye Diagram of the MS21147T as Driver and the MS21148T as Receiver:  $V_{CC}=3.3V$ , PRBS7 100Mbps CAT5E 10m



The Eye Diagram of the MS21147T as Driver and the MS21148T as Receiver:  $V_{CC}=3.3V$ , PRBS7 200Mbps CAT5E 4.5m



The Eye Diagram of the MS21147T as Driver and the MS21148T as Receiver:  $V_{CC}=3.3V$ , PRBS7 200Mbps CAT6E 10m

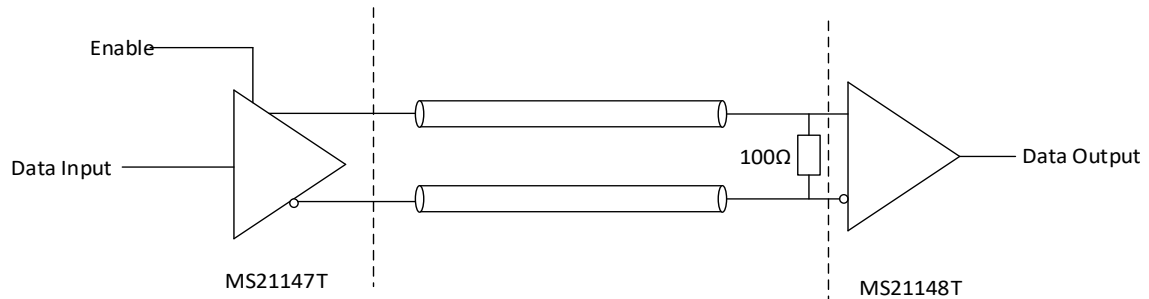
**FUNCTION DESCRIPTION**

The MS21147T is a four channel LVDS differential cable driver, meeting MLVDS amplitude characteristic. The technology reduces the amplitude of output voltage, improves switch speed and allows 3.3V power supply operation. Four current-mode driver all could provide 600mV peak-to-peak output voltage for 100Ω differential load. The MS21147T is applied for point-to-point and multi-point base-band data transmission through 100Ω controlled impedance media. The transmission media could be PCB traces, backplane or cables. The ultimate data rate and distance depend on the media attenuation characteristic, the noise coupled with environment and other system characteristics.

The MS21147T could receive TTL or CMOS logical level, and transform it to LVDS. The MS21147T also has three-state output function, controlled by EN and ENB pins. In addition, the power dissipation would decrease when the MS21147T is disabled. The enable function table is shown as follows.

Enable		Input	Output	
EN	ENB	DIN	DOUTP	DOUTN
H	L or Open	L	L	H
H	L or Open	H	H	L
Others		X	Z	Z

## TYPICAL APPLICATION DIAGRAM



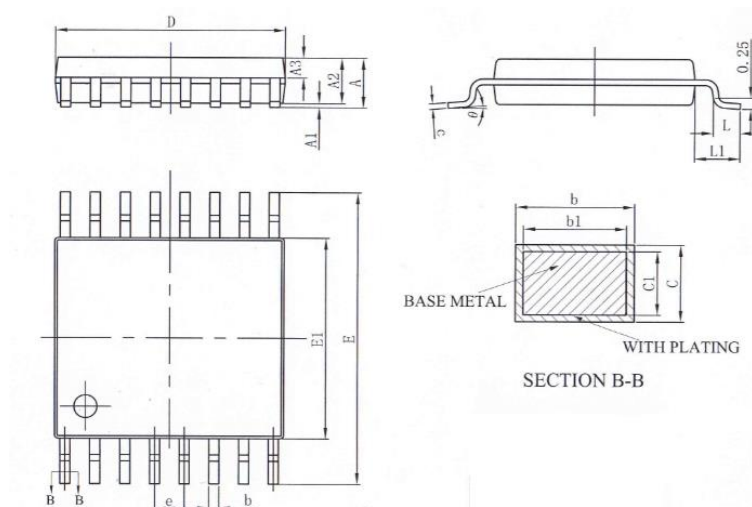
The typical application is shown as above. The MS21147T could act as driver for other LVDS receiver. The MS21147T has TSSOP package and the pin configuration makes it easy to perform PCB layout. The LVDS signal can easily match differential pair traces between driver and receiver. And the traces are allowed to be near with each other, in order to couple with noise as common-mode. The noise isolation is accomplished by the LVDS signal on one side of the device and the TTL signal on the other side.

### Transmission Distance

Normally, the MS21147T is used to cooperate with the MS21148T together. For CAT5E network line, at least 10 meters could be reached for data rate less than 100Mbps. While the rate increases to 200Mbps, the transmission distance would reduce to about 5 meters. When the transmission distance is less than 0.5 meter and the data rate is below 200Mbps, most cables could be used.

# PACKAGE OUTLINE DIMENSIONS

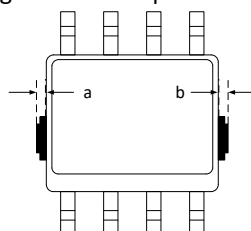
## TSSOP16



Symbol	Dimensions in Millimeters		
	Min	Typ	Max
A	-	-	1.20
A1	0.05	-	0.15
A2	0.90	1.00	1.05
A3	0.39	0.44	0.49
b	0.20	-	0.28
b1	0.19	0.22	0.25
c	0.13	-	0.17
c1	0.12	0.13	0.14
D	4.90	5.00	5.10
E	6.20	6.40	6.60
E1	4.30	4.40	4.50
e	0.65BSC		
L	0.45	0.60	0.75
L1	1.00BSC		
$\theta$	0°	-	8°

Note: In addition to the package size, a, b are allowed to have the maximum size of 0.15mm for waste glue simultaneously.

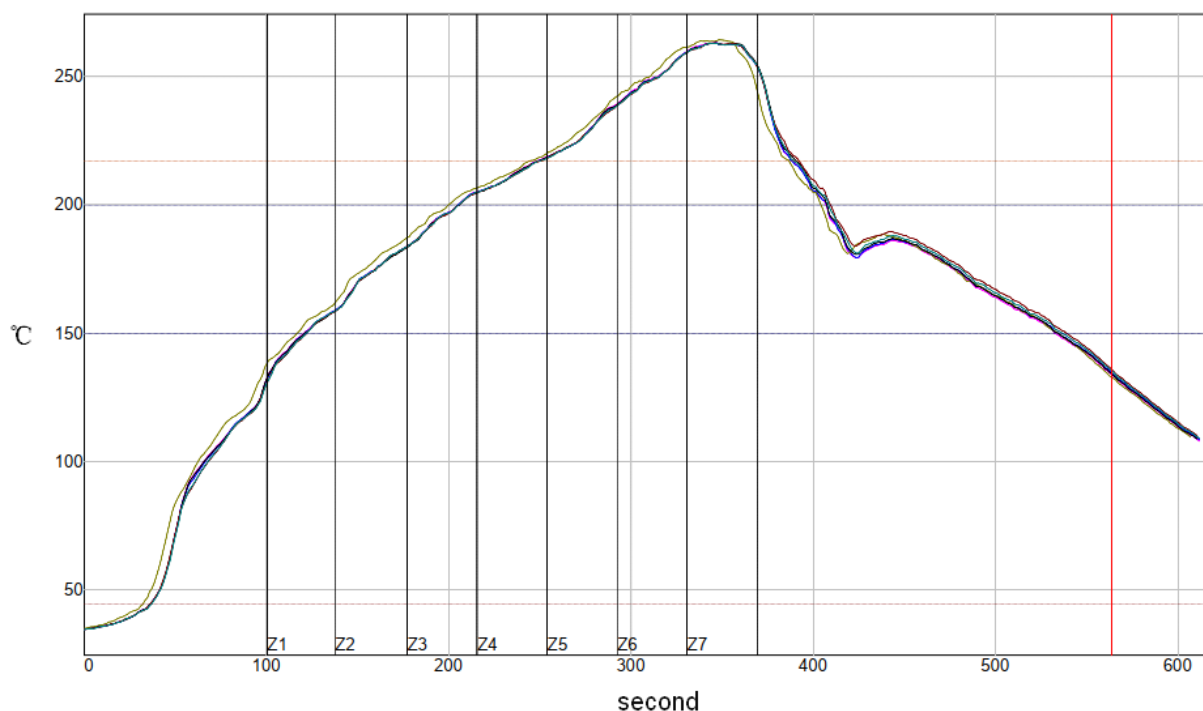
The diagram is as follows: taking SOP8 package as an example.



## REFLOW SOLDERING CURVE

Note that, only reflow solder supported.

Temperature Setting							
Temperature Zone	1	2	3	4	5	6	7
Up Temperature	183	214	221	243	241	275	295
Down Temperature	183	214	221	243	241	275	295
Conveyor Belt Speed (Centimeter Per Minute): 33.0							



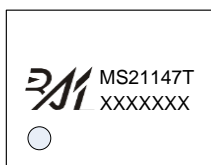
PWI= 68%	Maximum rising slope		Maximum falling slope		Preheating 150~200 °C		Maximum temperature		Total time above 217 °C		Time from peak 5 °C area		Peak time @25 °C	
VP 1	2.33	33%	-1.94	62%	82.78	-62%	263.50	13%	139.07	13%	36.05	7%	5.59	40%
VP 2	2.27	27%	-1.92	63%	82.96	-62%	263.22	10%	138.23	12%	36.70	11%	5.60	40%
VP 3	2.12	12%	-1.90	64%	81.77	-64%	264.38	25%	140.82	15%	34.98	-0%	5.72	43%
VP 4	2.32	32%	-1.88	65%	83.32	-61%	263.38	12%	140.76	15%	36.58	11%	5.59	40%
VP 5	2.13	13%	-1.80	68%	82.22	-63%	263.26	10%	140.65	15%	35.99	7%	5.61	40%
VP 6	2.18	18%	-1.90	64%	82.58	-62%	263.16	9%	138.91	13%	36.84	12%	5.60	40%
温差	0.21		0.14		1.55		1.22		2.59		1.86		0.13	

Process Limited

Solder Paste: 260			
Statistical Name:	Min	Max	Unit
Maximum Rising Slope	1.0	3.0	°C/second
Maximum Falling Slope	-6.0	-1.0	°C/second
Preheating150~200°C	60	180	Second
Maximum Temperature	255	270	°C
Total Time above 217°C	60	200	Second
Time from Peak 5°C Area	20	50	Second
Peak Time @25°C	0.0	8.0	Minute

## MARKING and PACKAGING SPECIFICATION

### 1. Marking Drawing Description



Product Name : MS21147T

Product Code : XXXXXXXX

### 2. Marking Drawing Demand

Laser printing, contents in the middle, font type Arial.

### 3. Packaging Specification

Device	Package	Piece/Reel	Reel/Box	Piece /Box	Box/Carton	Piece/Carton
MS21147T	TSSOP16	3000	1	3000	8	24000

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- The process of improving product is endless. And our company would sincerely provide more excellent product for customer.



**MOS CIRCUIT OPERATION PRECAUTIONS**

Static electricity can be generated in many places. The following precautions can be taken to effectively prevent the damage of MOS circuit caused by electrostatic discharge:

1. The operator shall ground through the anti-static wristband.
2. The equipment shell must be grounded.
3. The tools used in the assembly process must be grounded.
4. Must use conductor packaging or anti-static materials packaging or transportation.



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